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In 1969, the first triple operational transconductance amplifier or OTA was introduced. The wide acceptance of this new circuit concept prompted the development of the single, highly linear operational transconductance amplifier, the CA3080. Because of its extremely linear transconductance characteristics with respect to amplifier bias current, the CA3080 gained wide acceptance as a gain control block. The CA3094 improved on the performance of the CA3080 through the addition of a pair of transistors; these transistors extended the current carrying capability to 300 mA , peak. This new device, the CA3094, is useful in an extremely broad range of circuits in consumer and industrial applications; this paper describes only a few of the many consumer applications.

## What Is an OTA?

The OTA, operational transconductance amplifier, concept is as basic as the transistor; once understood, it will broaden the designer's horizons to new boundaries and make realizable designs that were previously unobtainable. Figure 1 shows an equivalent diagram of the OTA. The differential input circuit is the same as that found on many modern operational amplifiers. The remainder of the OTA is composed of current mirrors as shown in Figure 2. The geometry of these mirrors is such that the current gain is unity. Thus, by highly degenerating the current mirrors, the output current is precisely defined by the differential input amplifier. Figure 3 shows the output current transfer characteristic of the amplifier. The shape of this characteristic remains constant and is independent of supply voltage. Only the maximum current is modified by the bias current.


FIGURE 1. EQUIVALENT DIAGRAM OF THE OTA


FIGURE 2. CURRENT MIRRORS $\mathbf{W}, \mathrm{X}, \mathrm{Y}$ AND Z USED IN THE OTA


FIGURE 3. THE OUTPUT CURRENT TRANSFER CHARACTERISTIC OF THE OTA IS THE SAME AS THAT OF AN IDEALIZED DIFFERENTIAL AMPLIFIER

The major controlling factor in the OTA is the input amplifier bias current $\mathrm{I}_{\mathrm{ABC}}$; as explained in Figure 1, the total output current and $\mathrm{g}_{\mathrm{m}}$ are controlled by this current. In addition, the input bias current, input resistance, total supply current, and output resistance are all proportional to this amplifier bias current. These factors provide the key to the performance of this most flexible device, an idealized differential amplifier, i.e., a circuit in which differential input to single ended output conversion can be realized. With this knowledge of the basics of the OTA, it is possible to explore some of the applications of the device.

## DC Gain Control

The methods of providing DC gain control functions are numerous. Each has its advantage: simplicity, low cost, high level control, low distortion. Many manufacturers who have nothing better to offer propose the use of a four quadrant
multiplier. This is analogous to using an elephant to carry a twig. It may be elegant but it takes a lot to keep it going! When operated in the gain control mode, one input of the standard transconductance multiplier is offset so that only one half of the differential input is used; thus, one half of the multiplier is being thrown away.
The OTA, while providing excellent linear amplifier characteristics, does provide a simple means of gain control. For this application the OTA may be considered the realization of the ideal differential amplifier in which the full differential amplifier $g_{m}$ is converted to a single ended output. Because the differential amplifier is ideal, its $\mathrm{g}_{\mathrm{m}}$ is directly proportional to the operating current of the differential amplifier; in the OTA the maximum output current is equal to the amplifier bias current $I_{A B C}$. Thus, by varying the amplifier bias current, the amplifier gain may be varied: $A=g_{m} R_{L}$ where $R_{L}$ is the output load resistance. Figure 4 shows the basic configuration of the OTA DC gain control circuit.


FIGURE 4. BASIC CONFIGURATION OF THE OTA DC GAIN CONTROL CIRCUIT

As long as the differential input signal to the OTA remains under 50 mV peak-to-peak, the deviation from a linear transfer will remain under 5 percent. Of course, the total harmonic distortion will be considerably less than this value. Signal excursions beyond this point only result in an undesired "compressed" output. The reason for this compression can be seen in the transfer characteristic of the differential amplifier in Figure 3. Also shown in Figure 3 is a curve depicting the departure from a linear line of this transfer characteristic.

The actual performance of the circuit shown in Figure 4 is plotted in Figure 5. Both signal to noise ratio and total harmonic distortion are shown as a function of signal input. Figures 5B and 5C show how the signal handling capability of the circuit is extended through the connection of diodes on the input as shown in Figure 6 [2]. Figure 7 shows total system gain as a function of amplifier bias current for several values of diode current. Figure 8 shows an oscilloscope reproduction of the CA3080 transfer characteristic as applied to the circuit of Figure 4. The oscilloscope reproduction of Figure 9 was obtained with the circuit shown in Figure 6. Note
the improvement in linearity of the transfer characteristic. Reduced input impedance does result from this shunt connection. Similar techniques could be used on the OTA output, but then the output signal would be reduced and the correction circuitry further removed from the source of non linearity. It must be emphasized that the input circuitry is differential.


FIGURE 5A.


FIGURE 5B.


FIGURE 5. PERFORMANCE CURVES FOR THE CIRCUIT OF FIGURES 4 AND 6


Transistors from CA3046 array.
AGC System with extended input range.
FIGURE 6. A CIRCUIT SHOWING HOW THE SIGNAL HANDLING CAPABILITY OF THE CIRCUIT OF FIGURE 4 CAN BE EXTENDED THROUGH THE CONNECTION OF DIODES ON THE INPUT


Horizontal: $25 \mathrm{mV} /$ Div. Vertical: $50 \mu \mathrm{~A} /$ Div. $\mathrm{I}_{\mathrm{ABC}}=100 \mu \mathrm{~A}$

FIGURE 8. CA3080 TRANSFER CHARACTERISTIC FOR THE CIRCUIT OF FIGURE 4

## Simplified Differential Input to Single Ended Output Conversion

One of the more exacting configurations for operational amplifiers is the differential to single-ended conversion circuit. Figure 10 shows some of the basic circuits that are usually employed. The ratios of the resistors must be precisely matched to assure the desired common mode rejection. Figure 11 shows another system using the CA3080 to obtain this conversion without the use of precision resistors. Differential input signals must be kept under 126 mV for better than 5 percent nonlinearity. The


FIGURE 7. TOTAL SYSTEM GAIN vs AMPLIFIER BIAS CURRENT FOR SEVERAL VALUES OF DIODE CURRENT


Horizontal: $0.5 \mathrm{~V} /$ Div. Vertical: $50 \mu \mathrm{~A} /$ Div., $\mathrm{I}_{\mathrm{ABC}}=100 \mu \mathrm{~A}$, Diode Current $=1 \mathrm{~mA}$

FIGURE 9. CA3080 TRANSFER CHARACTERISTIC FOR THE CIRCUIT OF FIGURE 6
common mode range is that of the CA3080 differential amplifier. In addition, the gain characteristic follows the standard differential amplifier $g_{m}$ temperature coefficient of $-0.3 \% /{ }^{\circ} \mathrm{C}$. Although the system of Figure 11 does not provide the precise gain control obtained with the standard operational amplifier approach, it does provide a good simple compromise suitable for many differential transducer amplifier applications.


FIGURE 10. SOME TYPICAL DIFFERENTIAL TO SINGLE ENDED CONVERSION CIRCUITS

$A=g_{m} R_{L}$ at $500 \mu A, I_{A B C}:$
$g_{\mathrm{m}} \approx 10 \mathrm{mS}$.
$\therefore A=10 \mathrm{mS} \times 10 \mathrm{~K}=100$.

## FIGURE 11. A DIFFERENTIAL TO SINGLE ENDED CONVERSION CIRCUIT WITHOUT PRECISION RESISTORS

## The CA3094

The CA3094 offers a unique combination of characteristics that suit it ideally for use as a programmable gain block for audio power amplifiers. It is a transconductance amplifier in which gain and open-loop bandwidth can be controlled between wide limits. The device has a large reserve of output-current capability, and breakdown and power dissipation ratings sufficiently high to allow it to drive a complementary pair of transistors. For example, a 12 W power amplifier stage ( $8 \Omega$ load) can be driven with peak currents of 35 mA (assuming a minimum output transistor beta of 50 ) and supply voltages of $\pm 18 \mathrm{~V}$. In this application, the CA3094A is operated substantially below its supply voltage rating of 44 V max. and its dissipation rating of 1.6 W max. Also in this application, a high value of open-loop gain suggests the possibility of precise adjustment of frequency response characteristics by adjustment of impedances in the feedback networks.

## Implicit Tone Controls

In addition to low distortion, the large amount of loop gain and flexibility of feedback arrangements available when using the CA3094 make it possible to incorporate the tone controls into the feedback network that surrounds the entire amplifier system. Consider the gain requirements of a phonograph playback system that uses a typical high quality magnetic cartridge[3]. A desirable system gain would result in from 2 W to 5 W of output at a recorded velocity of $1 \mathrm{~cm} / \mathrm{s}$. Magnetic pickups have outputs typically ranging from 4 mV to 10 mV at $5 \mathrm{~cm} / \mathrm{s}$. To get the desired output, the total system needs about 72 dB of voltage gain at the reference frequency.

Figure 12 is a block diagram of a system that uses a passive or "losser" type of tone control circuit that is inserted ahead of the gain control. Figure 13 shows a system in which the tone controls are implicit in the feedback circuits of the power amplifier. Both systems assume the same noise input voltage at the equalizer and main-amplifier inputs. The feedback system shows a small improvement ( 3.8 dB ) in signal-to-noise ratio at maximum gain but a dramatic improvement $(20 \mathrm{~dB})$ at the zero gain position. For purposes of comparison, the assumption is made that the tone controls are set "flat" in both cases.

## Cost Advantages

In addition to the savings resulting from reduced parts count and circuit size, the use of the CA3094 leads to further savings in the power supply system. Typical values of power supply rejection and common-mode rejection are 90 dB and 100 dB , respectively. An amplifier with 40 dB of gain and 90 dB of power supply rejection would require 316 mV of power supply ripple to produce 1 mV of hum at the output. Thus, no further filtering is required other than that given by the energy storage capacitor at the output of the rectifier system.


FIGURE 12. BLOCK DIAGRAM OF A SYSTEM USING A "LOSSER" TYPE TONE CONTROL CIRCUIT


FIGURE 13. A SYSTEM IN WHICH TONE CONTROLS ARE IMPLICIT IN THE FEEDBACK CIRCUIT OF THE POWER AMPLIFIER

## Power Amplifier Using the CA3094

A complete power amplifier using the CA3094 and three additional transistors is shown schematically in Figure 14. The amplifier is shown in a single-channel configuration, but power supply values are designed to support a minimum of two channels. The output section comprises $Q_{1}$ and $Q_{2}$, complementary epitaxial units connected in the familiar "bootstrap" arrangement. Capacitor $\mathrm{C}_{3}$ provides added base drive for $Q_{1}$ during positive excursions of the output. The circuit can be operated from a single power supply as well as from a split supply as shown in Figure 15. The changes required for 14.4 V operation with a $3.2 \Omega$ speaker are also indicated in the diagram.

The amplifier may also be modified to accept input from ceramic phonograph cartridges. For standard inputs (equalizer preamplifiers, tuners, etc.) $\mathrm{C}_{1}$ is $0.047 \mu \mathrm{~F}, \mathrm{R}_{1}$ is $250 k \Omega$, and $R_{2}$ and $C_{2}$ are omitted. For ceramic-cartridge inputs, $\mathrm{C}_{1}$ is $0.0047 \mu \mathrm{~F}, \mathrm{R}_{1}$ is $2.5 \mathrm{M} \Omega$, and the jumper across $\mathrm{C}_{2}$ is removed.

## Output Biasing

Instead of the usual two-diode arrangement for establishing idling currents in $\mathrm{Q}_{1}$ and $\mathrm{Q}_{2}$, a " $\mathrm{V}_{\mathrm{be}}$ Multiplier", transistor $\mathrm{Q}_{3}$, is used. This method of biasing establishes the voltage between the base of $Q_{1}$ and the base of $Q_{2}$ at a constant multiple of the base to emitter voltage of a single transistor while maintaining a low variational impedance between its collector and emitter (see Appendix $A$ ). If transistor $Q_{3}$ is mounted in intimate thermal contact with the output units, the operating temperature of the heat sink forces the $V_{b e}$ of $Q_{3}$ up and down inversely with heat-sink temperature. The voltage bias between the bases of $Q_{1}$ and $Q_{2}$ varies inversely with heat sink temperature and tends to keep the idling current in $Q_{1}$ and $Q_{2}$ constant.

A bias arrangement that can be accomplished at lower cost than those already described replaces the $\mathrm{V}_{\text {be }}$ multiplier with a 1N5391 diode in series with an $8.2 \Omega$ resistor. This arrangement does not provide the degree of bias stability of the $\mathrm{V}_{\text {be }}$ multiplier, but is adequate for many applications.

## Tone-Controls

The tone controls, the essential elements of the feedback system, are located in two sets of parallel paths. The bass network includes $R_{3}, R_{4}, R_{5}, C_{4}$, and $C_{5} . C_{6}$ blocks the $D C$ from the feedback network so that the DC gain from input to the feedback takeoff point is unity. The residual DC output voltage at the speaker terminals is then
$\left(R_{1} \frac{R_{11}+R_{12}}{R_{12}}\right) I_{A B C}$
where $R_{1}$ is the source resistance. The input bias current is then
$\frac{\mathrm{I}_{\mathrm{ABC}}}{2 \beta}=-\frac{\left(\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{BE}}\right)}{2 \beta \mathrm{R}_{6}}$
The treble network consists of $\mathrm{R}_{7}, \mathrm{R}_{8}, \mathrm{R}_{9}, \mathrm{R}_{10}, \mathrm{C}_{7}, \mathrm{C}_{8}, \mathrm{C}_{9}$, and $C_{10}$. Resistors $R_{7}$ and $R_{9}$ limit the maximum available cut and boost, respectively. The boost limit is useful in curtailing heating due to finite turn-off time in the output units. The limit is also desirable when there are tape recorders nearby. The cut limit aids the stability of the amplifier by cutting the loop gain at higher frequencies where phase shifts become significant.

In cases in which absolute stability under all load conditions is required, it may be necessary to insert a small inductor in the output lead to isolate the circuit from capacitive loads. A $3 \mu \mathrm{H}$ inductor ( 1 A ) in parallel with a $22 \Omega$ resistor is adequate. The derivation of circuit constants is shown in Appendix B. Curves of control action versus electrical rotation are also given.


FIGURE 14. A COMPLETE POWER AMPLIFIER USING THE CA3094 AND THREE ADDITIONAL TRANSISTORS


FIGURE 15. A POWER AMPLIFIER OPERATED FROM A SINGLE SUPPLY

## Performance

Figure 16 is a plot of the measured response of the complete amplifier at the extremes of tone control rotation. A comparison of Figure 16 with the computed curves of Figure B4 (Appendix B) shows good agreement. The total harmonic distortion of the amplifier with an unregulated power supply is shown in Figure 17; IM distortion is plotted in Figure 18. Hum and noise are typically $700 \mu \mathrm{~V}$ at the output, or 83 dB down.


FIGURE 16. THE MEASURED RESPONSE OF THE AMPLIFIER AT EXTREMES OF TONE CONTROL ROTATION


FIGURE 17. TOTAL HARMONIC DISTORTION OF THE AMPLIFIER WITH AN UNREGULATED POWER SUPPLY


FIGURE 18. IM DISTORTION OF THE AMPLIFIER WITH AN UNREGULATED SUPPLY

## Companion RIAA Preamplifier

Many available preamplifiers are capable of providing the drive for the power amplifier of Figure 14. Yet the unique characteristics of the amplifier, its power supply, input impedance, and gain make possible the design of an RIAA preamplifier that can exploit these qualities. Since the input impedance of the amplifier is essentially equal to the value of the volume control resistance ( $250 \mathrm{k} \Omega$ ), the preamplifier need not have high output current capability. Because the gain of the power amplifier is high ( 40 dB ) the preamplifier gain only has to be approximately 30 dB at the reference frequency ( 1 kHz ) to provide optimum system gain.
Figure 19 shows the schematic diagram of a CA3080 preamplifier. The CA3080, a low cost OTA, provides sufficient open-loop gain for all the bass boost necessary in RIAA compensation. For example, a $g_{m}$ of 10 mS with a load resistance of $250 \mathrm{k} \Omega$ provides an open-loop gain of 68 dB , thus allowing at least 18 dB of loop gain at the lowest frequency. The CA3080 can be operated from the same power supply as the main amplifier with only minimal decoupling because of the high power supply rejection inherent in the device circuitry. In addition, the high voltage swing capability at the output enables the CA3080 preamplifier to handle badly over modulated (over-cut) recordings without overloading. The accuracy of equalization is within $\pm 1 \mathrm{~dB}$ of the RIAA curve, and distortion is virtually immeasurable by classical methods. Overload occurs at an output of 7.5 V , which allows for undistorted inputs of up to 186 mV (260mV peak).


FIGURE 19. A CA3080 PREAMPLIFIER

## Appendix A - $V_{\text {be }}$ Multiplier

The equivalent circuit for the $\mathrm{V}_{\mathrm{be}}$ multiplier is shown in Figure A1. The voltage E1 is given by:

$$
\begin{equation*}
E_{1}=\frac{R_{1} I}{\beta+1}+V_{b e}\left[1+\frac{R_{1}}{R_{2}(\beta+1)}\right] \tag{EQ.A1}
\end{equation*}
$$



FIGURE A1. EQUIVALENT CIRCUIT FOR THE $\mathrm{V}_{\mathrm{be}}$ MULTIPLIER
The value of $\mathrm{V}_{\mathrm{be}}$ is itself dependent on the emitter current of the transistor, which is, in turn, dependent on the input current I since:
$I_{e}=I-\frac{V_{b e}}{R_{2}}$
(EQ. A2)

The derivative of Equation A1 with respect to I yields the incremental impedance of the $\mathrm{V}_{\mathrm{be}}$ multiplier:
$\frac{d E_{1}}{d l}=Z=\frac{R_{1}}{\beta+1}+\left[1+\frac{B R_{1}}{(\beta+1) R_{2}}\right]\left[\frac{K_{3} R_{2}}{R_{2} l^{2}+K_{3}}\right]$
where $K_{3}$ is a constant of the transistor $Q_{1}$ and can be found from:

$$
\begin{equation*}
V_{b e}=K_{3} \operatorname{In} I_{e}-K_{2} \tag{EQ.A4}
\end{equation*}
$$

Equation A4 is but another form of the diode equation:
$I_{e}=I_{S} e^{\left[\frac{q V_{b e}}{K T}-1\right]}$
Using the values shown in Figure 14, plus data on the 2N6292 (a typical transistor that could be used in the circuit), the dynamic impedance of the circuit at a total current of 40 mA is found to be $4.6 \Omega$. In the actual design of the $V_{b e}$ multiplier, the value of $\mathrm{IR}_{2}$ must be greater than $\mathrm{V}_{\mathrm{be}}$ or the transistor will never become forward biased.

## Appendix B - Tone Controls

Figure B1 shows four operational amplifier circuit configurations and the gain expressions for each. The asymptotic low frequency gain is obtained by letting $S$ approach zero in each case:

Bass Boost: $A_{\text {LOW }}=\frac{R_{1}+R_{2}+R_{3}}{R_{2}}$
Bass Cut: $A_{\text {LOW }}=\frac{R_{1}+R_{2}+R_{3}}{R_{2}+R_{3}}$
Treble Boost: $A_{\text {LOW }}=\frac{C_{1}+C_{4}}{C_{4}}$
Treble Cut: $A_{\text {LOW }}=\frac{C_{1}+C_{4}}{C_{4}}$
The asymptotic high-frequency gain is obtained by letting S increase without limit in each expression:
Bass Boost: $A_{\text {HIGH }}=\frac{R_{1}+R_{2}}{R_{2}}$
Bass Cut: $A_{\text {HIGH }}=\frac{R_{1}+R_{2}}{R_{2}}$
Treble Boost: $\mathrm{A}_{\text {HIGH }}=1+\mathrm{C}_{1}\left(\frac{\mathrm{C}_{3}+\mathrm{C}_{4}}{\mathrm{C}_{3} \mathrm{C}_{4}}\right)$
Treble Cut: $A_{\text {HIGH }}=\frac{C_{2}+\frac{C_{1} C_{4}}{C_{1}+C_{4}}}{C_{1}+C_{2}}$

Note that the expressions for high frequency gain are identical for both bass circuits, while the expressions for low frequency gain are identical for the treble circuits.

Figure B2 shows cut and boost bass and treble controls that have the characteristics of the circuits of Figure B1. The value $R_{\text {EFF }}$ in the treble controls of Figure B 1 is derived from the parallel combination of $R_{1}$ and $R_{2}$ of Figure $B 2$ when the control is rotated to its maximum counterclockwise position. When the control is rotated to its maximum clockwise position, the value is equal to $\mathrm{R}_{1}$.

To compute the circuit constants, it is necessary to decide in advance the amounts of boost and cut desired. The gain expressions of Figure B1 indicate that the slope of the amplitude versus frequency curve in each case will be 6 dB per octave ( 20 dB per decade). If the ratios of boosted and cut gain are set at 10, i.e.


$$
\begin{gathered}
A=\left(\frac{R_{1}+R_{2}+R_{3}}{R_{2}}\right)\left[\frac{1+S C_{1} \frac{\left(R_{2} R_{3}+R_{1} R_{3}\right)}{\left(R_{1}+R_{2}+R_{3}\right)}}{1+S R_{3} C_{1}}\right] \\
A_{\text {LOW FREQUENCY }}=\frac{R_{1}+R_{2}+R_{3}}{R_{2}}
\end{gathered}
$$

FIGURE B1 (A). BASS BOOST


$$
\begin{gathered}
A=\left(\frac{C_{1}+C_{4}}{C_{4}}\right)\left[\frac{1+\mathrm{SR}_{\mathrm{EFF}} \frac{\left(\mathrm{C}_{1} \mathrm{C}_{4}+\mathrm{C}_{3} \mathrm{C}_{4}+\mathrm{C}_{1} \mathrm{C}_{3}\right)}{\left(\mathrm{C}_{1}+\mathrm{C}_{4}\right)}}{1+\mathrm{SR}_{\mathrm{EFF}_{3} \mathrm{C}_{3}}}\right] \\
\mathrm{A}_{\text {LOW FREQUENCY }}=\frac{\mathrm{C}_{1}+\mathrm{C}_{4}}{\mathrm{C}_{4}}
\end{gathered}
$$

FIGURE B1 (C). TREBLE BOOST
FIGURE B1. FOUR OPERATIONAL AMPLIFIER CIRCUIT CONFIGURATIONS AND THE GAIN EXPRESSIONS FOR EACH

The unaffected portion of the gain ( $\mathrm{A}_{\text {HIGH }}$ for the bass control and $A_{\text {LOW }}$ for the treble control) is 11 in each case.

To make the controls work symmetrically, the low and high frequency break points must be equal for both boost and cut.

Thus:
Bass Control: $\frac{C_{1} R_{3}\left(R_{1}+R_{2}\right)}{R_{1}+R_{2}+R_{3}}=\frac{C_{2} R_{2} R_{3}}{R_{2}+R_{3}}$
and $C_{1} R_{3}=\frac{C_{2} R_{3}\left(R_{1}+R_{2}\right)}{R_{1}+R_{2}+R_{3}}$
since $R_{3} \cong R_{2}+R_{3}, \quad C 2=10 C_{1}$
Treble Control: $\mathrm{R}_{1} \frac{\left(\mathrm{C}_{1} \mathrm{C}_{4}+\mathrm{C}_{3} \mathrm{C}_{4}+\mathrm{C}_{1} \mathrm{C}_{3}\right)}{\mathrm{C}_{1}+\mathrm{C}_{4}}$
$=\frac{R_{1} R_{2}}{R_{1}+R_{2}}\left(C_{1}+C_{2}\right)$
and $R_{2} C_{3}=\left(\frac{R_{1} R_{2}}{R_{1}+R_{2}}\right) \frac{\left(C_{1} C_{4}+C_{2} C_{4}+C_{1} C_{2}\right)}{\left(C_{1}+C_{4}\right)}$
since $C_{1} \cong 100 C_{2}, C_{2}=C_{3}$ and $C_{1}=10 C_{4}, R_{1}=9 R_{2}$
To make the controls work in the circuit of Figure 14, breaks were set at 1000 Hz :
for the base control $0.1 \mathrm{C}_{1} \mathrm{R}_{3}=\frac{1}{2 \pi \times 1000}$
and for the treble control $\mathrm{R}_{1} \mathrm{C}_{3}=\frac{1}{2 \pi \times 1000}$

## Response and Control Rotation

In a practical design, it is desirable to make "flat" response correspond to the $50 \%$ rotation position of the control, and to have an aural sensation of smooth variation of response on either side of the mechanical center. It is easy to show that the "flat" position of the bass control occurs when the wiper arm is advanced to $91 \%$ of its total resistance. The amplitude response of the treble control is, however, never completely "flat"; a computer was used to generate response curves as controls were varied.

Figure B3 is a plot of the response with bass and treble tone controls combined at various settings of both controls. The values shown are the practical ones used in the actual design. Figure B4 shows the information of Figure B3 replotted as a function of electrical rotation. The ideal taper for each control would be the complement of the 100 Hz plot for the bass control and the 10 kHz response for the treble control. The mechanical center should occur at the crossover point in each case.


FIGURE B2 (A). BASS CONTROL


FIGURE B2 (B). TREBLE CONTROL
FIGURE B2. CUT AND BOOST BASS AND TREBLE CONTROLS THAT HAVE THE CHARACTERISTICS OF THE CIRCUITS IN FIGURE B1

FIGURE B3. A PLOT OF THE RESPONSE OF THE CIRCUIT OF FIGURE 14 WITH BASS AND TREBLE TONE CONTROLS COMBINED AT VARIOUS SETTINGS OF BOTH CONTROLS


FIGURE B4 (A).

## References

For Intersil documents available on the internet, see web site http://www.intersil.com/
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Transconductance Amplifiers," H. A. Wittlinger, Intersil Corporation.
[2] "A New Wide-Band Amplifier Technique,"B. Gilbert, IEEE Journal of Solid State Circuits, Vol. SC-3, No. 4, December, 1968.
[3] "Trackability," James A. Kogar, Audio, December, 1966.


FIGURE B4 (B).
FIGURE B4. THE INFORMATION OF FIGURE B3 PLOTTED AS A FUNCTION OF ELECTRICAL ROTATION

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